

DESCRIPTION

The 2SD596-V1, 2SD596-V2, 2SD596-V3, 2SD596-V4 and 2SD596-V5 are available in the SOT-23 package.

ORDERING INFORMATION

Package Type	Part Number		
SOT-23	2SD596-V1		
	2SD596-V2		
	2SD596-V3		
	2SD596-V4		
	2SD596-V5		
SPQ	3,000pcs/Reel		
AiT provides all RoHS Compliant Products			

h_{FE} CLASSIFICATION

Rank	Range
V1	110 ~ 180
V2	135 ~ 220
V3	170 ~ 270
V4	200 ~ 320
V5	250 ~ 400

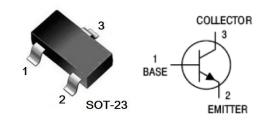
FEATURE

- · Micro package.
- · Complementary to 2SB624 PNP transistor.
- High DC current gain h_{FE} : 200TYP. (V_{CE} =1.0V, I_{C} =100mA)

APPLICATION

Audio frequency general purpose amplifier applications.

PIN DESCRIPTION



PIN#	DESCRIPTION		
1	Base		
2	Emitter		
3	Collector		

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise specified.

30 V
25 V
5 V
700 mA
200 mW
-55 ~ 150 °C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 T_A =25°C unless otherwise specified.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-Base Breakdown Voltage	V _(BR) CBO	I _C = 100 uA,	30	-	-	V
		I _E = 0				
Collector-Emitter Breakdown Voltage	V _(BR) CEO	$I_C = 1 \text{ mA},$	25	1	-	V
		I _B = 0				
Collector-Base Breakdown Voltage	V _{(BR)EBO}	I _E = 100 uA,	5	-	-	V
	V (BR)EBO	I _C = 0				
Collector Cut-off Current	Ісво	$V_{CB} = 30 \text{ V},$	-	-	0.1	uA
Collector Cut-on Current	ICBO	I _E = 0				
Emitter Cut-off Current	I _{EBO}	V _{EB} = 5 V,	-	-	0.1	uA
Emitter Gut-on Gurrent		I _C = 0				
		V _{CE} = 1 V,	110 50	200	400	
DC Current Gain	h _{FE}	I _C = 100 mA				
		V _{CE} = 1 V,		-	-	
		I _C = 700 mA				
Callacter Freitter Ceturation Voltage	V _{CE(sat)}	I _C = 700 mA,	-	0.22	0.6	V
Collector-Emitter Saturation Voltage		$I_B = 70 \text{ mA},$				
Rasa Emitter Voltage	V _{BE}	V _{CE} = 6 V,	600	640	700	V
Base-Emitter Voltage		$I_{C} = 10 \text{ mA},$				
Transition Frequency	f⊤	V _{CE} = 6 V,	170	-	-	MHz
		I _E = -10 mA				
Output capacitance	Cob	V _{CB} = 6 V,	-	12	-	pF
		I _E = 0				
		f = 10 kHz				



TYPICAL CHARACTERISTICS

Fig 1. Total power dissipation vs.

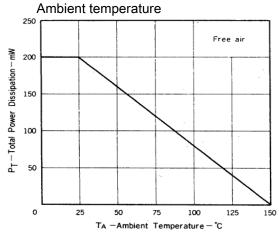


Fig 3. Collector and base saturation voltage vs.

Collector current

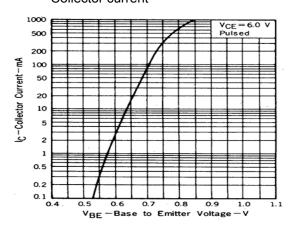


Fig 5. Collector current vs. Base to emitter voltage

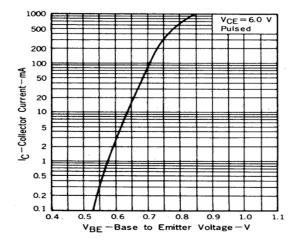


Fig 2. Collector current vs. Collector to emitter voltage

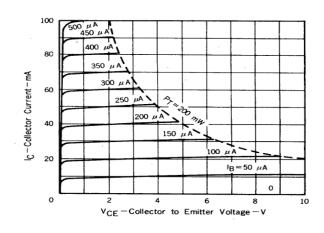


Fig 4. Current to emitter voltage vs. Base current

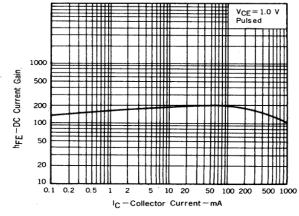
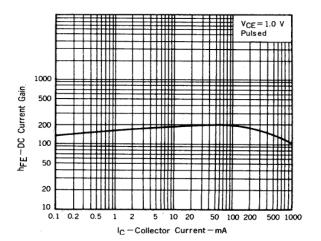


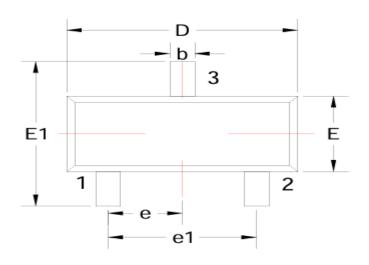
Fig 5. DC current gain vs. Collector current

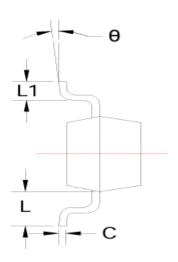


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PACKAGE INFORMATION

Dimension in SOT-23 (Unit: mm)







Comple ed	Millin	neter		
Symbol	Min.	Max.		
Α	0.900	1.150		
A1	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е	0.950 TYP.			
e1	1.800	2.000		
L	0.550 REF			
L1	0.300	0.500		
θ	0°	8°		

2SD596 TRANSISTOR SILICON NPN EPITAXIAL PLANAR TRANSISTOR

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